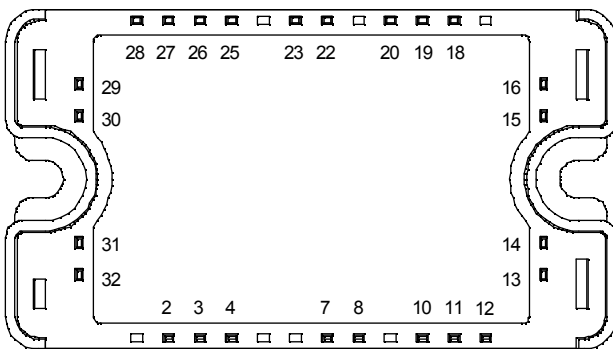
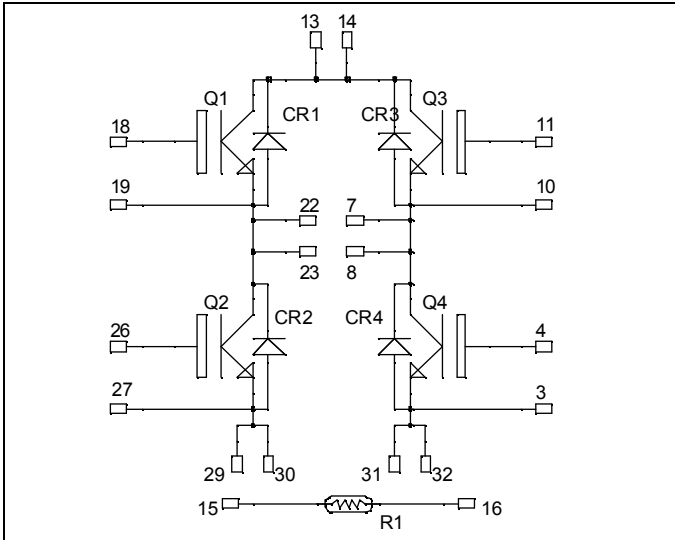


**Full - Bridge  
Trench + Field Stop IGBT®  
Power Module**

**$V_{CES} = 600V$   
 $I_C = 20A @ T_c = 80^\circ C$**



All multiple inputs and outputs must be shorted together  
Example: 13/14 ; 29/30 ; 22/23 ...

**Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

**Features**

- Trench + Field Stop IGBT® Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - Avalanche energy rated
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
- High level of integration
- Internal thermistor for temperature monitoring

**Benefits**

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability

**Absolute maximum ratings**

| Symbol    | Parameter                             | Max ratings         | Unit       |
|-----------|---------------------------------------|---------------------|------------|
| $V_{CES}$ | Collector - Emitter Breakdown Voltage | 600                 | V          |
| $I_C$     | Continuous Collector Current          | $T_C = 25^\circ C$  | 32         |
|           |                                       | $T_C = 80^\circ C$  | 20         |
| $I_{CM}$  | Pulsed Collector Current              | $T_C = 25^\circ C$  | 40         |
| $V_{GE}$  | Gate - Emitter Voltage                | $\pm 20$            | V          |
| $P_D$     | Maximum Power Dissipation             | $T_C = 25^\circ C$  | 62         |
| RBSOA     | Reverse Bias Safe Operating Area      | $T_J = 150^\circ C$ | 40A @ 550V |

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

| Symbol        | Characteristic                       | Test Conditions                               | Min                       | Typ | Max | Unit          |
|---------------|--------------------------------------|---|---------------------------|-----|-----|---------------|
| $I_{CES}$     | Zero Gate Voltage Collector Current  | $V_{GE} = 0\text{V}$ , $V_{CE} = 600\text{V}$ |                           |     | 250 | $\mu\text{A}$ |
| $V_{CE(sat)}$ | Collector Emitter Saturation Voltage | $V_{GE} = 15\text{V}$<br>$I_C = 20\text{A}$   | $T_j = 25^\circ\text{C}$  | 1.5 | 1.9 | V             |
|               |                                      |   | $T_j = 150^\circ\text{C}$ | 1.7 |     |               |
| $V_{GE(th)}$  | Gate Threshold Voltage               | $V_{GE} = V_{CE}$ , $I_C = 300\mu\text{A}$    | 5.0                       | 5.8 | 6.5 | V             |
| $I_{GES}$     | Gate – Emitter Leakage Current       | $V_{GE} = 20\text{V}$ , $V_{CE} = 0\text{V}$  |                           |     | 300 | nA            |

**Dynamic Characteristics**

| Symbol       | Characteristic               | Test Conditions                                      | Min | Typ  | Max | Unit |
|--------------|------------------------------|--|-----|------|-----|------|
| $C_{ies}$    | Input Capacitance            | $V_{GE} = 0\text{V}$                                 |     | 1100 |     | pF   |
| $C_{oes}$    | Output Capacitance           | $V_{CE} = 25\text{V}$                                |     | 70   |     |      |
| $C_{res}$    | Reverse Transfer Capacitance | $f = 1\text{MHz}$                                    |     | 35   |     |      |
| $T_{d(on)}$  | Turn-on Delay Time           | Inductive Switching ( $25^\circ\text{C}$ )           |     | 110  |     | ns   |
| $T_r$        | Rise Time                    | $V_{GE} = \pm 15\text{V}$<br>$V_{Bus} = 300\text{V}$ |     | 45   |     |      |
| $T_{d(off)}$ | Turn-off Delay Time          | $I_C = 20\text{A}$                                   |     | 200  |     |      |
| $T_f$        | Fall Time                    | $R_G = 18\Omega$                                     |     | 40   |     |      |
| $T_{d(on)}$  | Turn-on Delay Time           | Inductive Switching ( $150^\circ\text{C}$ )          |     | 120  |     | ns   |
| $T_r$        | Rise Time                    | $V_{GE} = \pm 15\text{V}$<br>$V_{Bus} = 300\text{V}$ |     | 50   |     |      |
| $T_{d(off)}$ | Turn-off Delay Time          | $I_C = 20\text{A}$                                   |     | 250  |     |      |
| $T_f$        | Fall Time                    | $R_G = 18\Omega$                                     |     | 60   |     |      |
| $E_{on}$     | Turn-on Switching Energy     |  |     | 0.35 |     | mJ   |
| $E_{off}$    | Turn-off Switching Energy    |  |     | 0.7  |     |      |

**Reverse diode ratings and characteristics**

| Symbol      | Characteristic                          | Test Conditions                            | Min                       | Typ | Max | Unit          |
|-------------|---|--|---------------------------|-----|-----|---------------|
| $V_{RRM}$   | Maximum Peak Repetitive Reverse Voltage |  | 600                       |     |     | V             |
| $I_{RM}$    | Maximum Reverse Leakage Current         | $V_R = 600\text{V}$                        | $T_j = 25^\circ\text{C}$  |     | 250 | $\mu\text{A}$ |
|             |   |  | $T_j = 150^\circ\text{C}$ |     | 500 |               |
| $I_{F(AV)}$ | Maximum Average Forward Current         | 50% duty cycle                             | $T_c = 80^\circ\text{C}$  | 20  |     | A             |
| $V_F$       | Diode Forward Voltage                   | $I_F = 20\text{A}$<br>$V_{GE} = 0\text{V}$ | $T_j = 25^\circ\text{C}$  | 1.6 | 2   | V             |
|             |   |  | $T_j = 150^\circ\text{C}$ | 1.5 |     |               |
| $t_{rr}$    | Reverse Recovery Time                   | $I_F = 20\text{A}$<br>$V_R = 300\text{V}$  | $T_j = 25^\circ\text{C}$  | 120 |     | ns            |
|             |   |  | $T_j = 150^\circ\text{C}$ | 210 |     |               |
| $Q_{rr}$    | Reverse Recovery Charge                 | $di/dt = 1600\text{A}/\mu\text{s}$         | $T_j = 25^\circ\text{C}$  | 1.1 |     | $\mu\text{C}$ |
|             |   |  | $T_j = 150^\circ\text{C}$ | 2.3 |     |               |

**Temperature sensor NTC** (see application note APT0406 on [www.advancedpower.com](http://www.advancedpower.com) for more information).

| Symbol             | Characteristic             | Min | Typ  | Max | Unit |
|--------------------|----------------------------|-----|------|-----|------|
| R <sub>25</sub>    | Resistance @ 25°C          |     | 50   |     | kΩ   |
| B <sub>25/85</sub> | T <sub>25</sub> = 298.15 K |     | 3952 |     | K    |

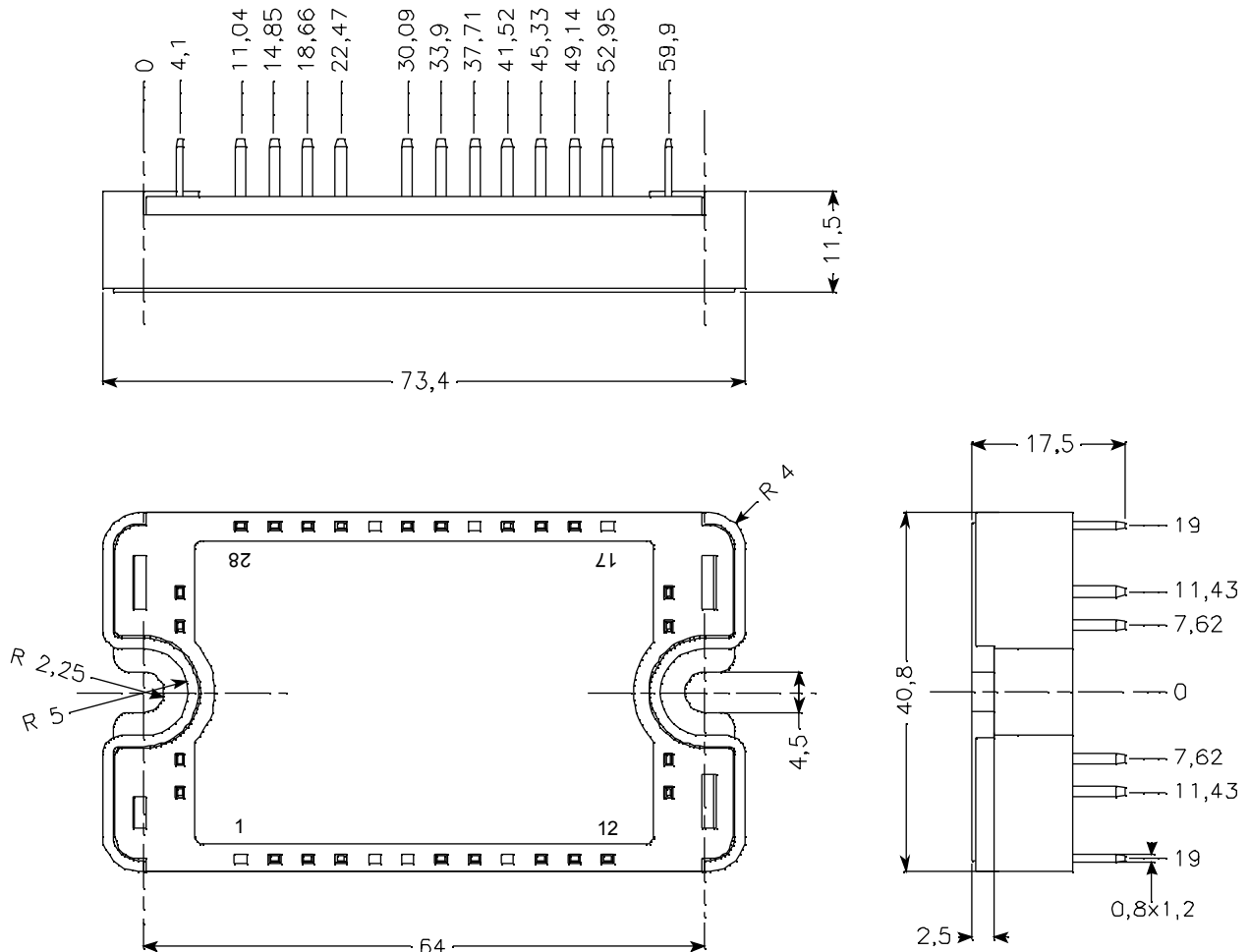
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

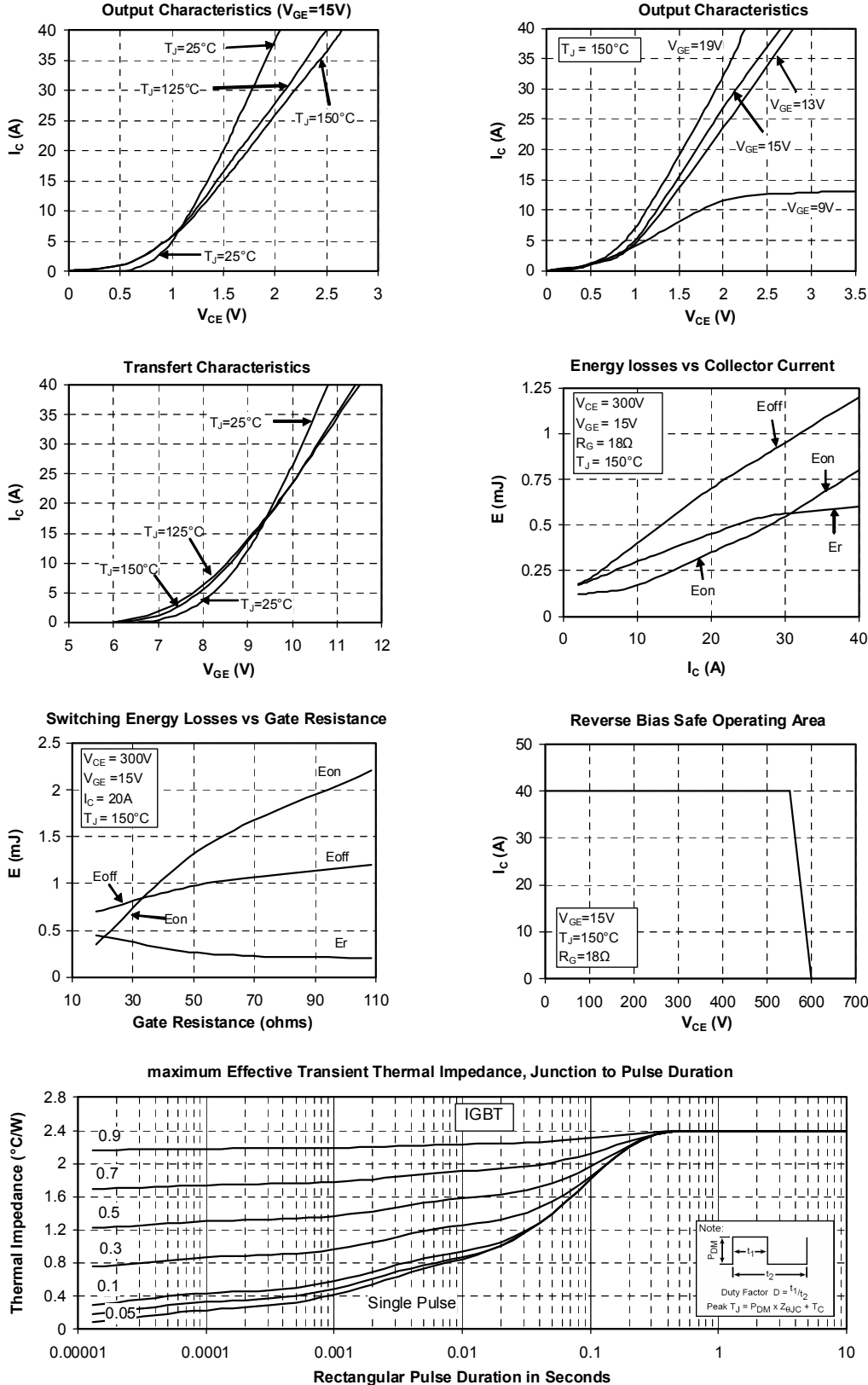
**Thermal and package characteristics**

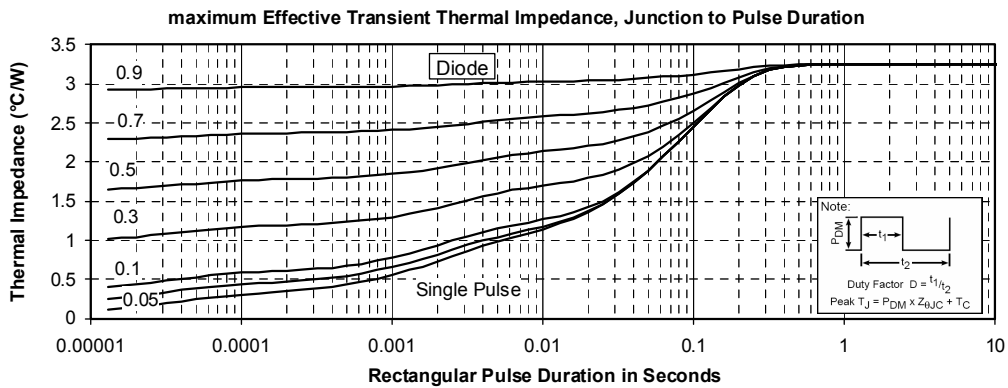
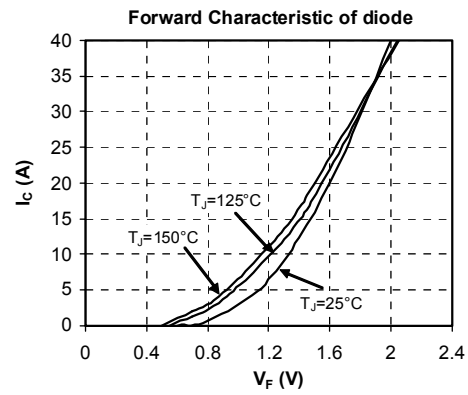
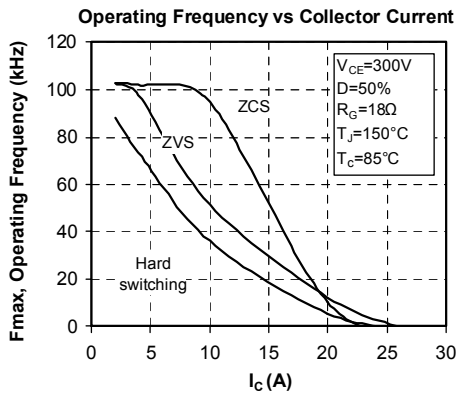
| Symbol            | Characteristic  | Min         | Typ | Max  | Unit |     |
|-------------------|---|-------------|-----|------|------|-----|
| R <sub>thJC</sub> | Junction to Case  | IGBT        |     | 2.4  | °C/W |     |
|                   |   | Diode       |     | 3.25 |      |     |
| V <sub>ISOL</sub> | RMS Isolation Voltage, any terminal to case t = 1 min, I <sub>isol</sub> < 1mA, 50/60Hz | 2500        |     |      | V    |     |
| T <sub>J</sub>    | Operating junction temperature range  | -40         |     | 175  | °C   |     |
| T <sub>STG</sub>  | Storage Temperature Range   | -40         |     | 125  |      |     |
| T <sub>C</sub>    | Operating Case Temperature  | -40         |     | 100  |      |     |
| Torque            | Mounting torque   | To heatsink | M4  | 1.5  | 4.7  | N.m |
| Wt                | Package Weight  |             |     |      | 110  | g   |

**Package outline** (dimensions in mm)



**Typical Performance Curve**





APT reserves the right to change, without notice, the specifications and information contained herein

APT's products are covered by one or more of U.S. patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.